Declaration and Power of Attorney For Patent Application **English Language Declaration**

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name,

first and joint inventor which a patent SEMICONDUCTOR TEST SYSTEM F	ntor (if plural nan is sought on the R DEVICES, if FOR CARRYIN	d sole inventor (if only one names are listed below) of the substitution entitled PRODUCT SEMICONDUCTOR DEVICES GOUT YIELD—RATE TEST	ject matter which is ION PROCESS FO PRODUCED THEI	claimed and OR PRODUC REBY, AND OF SUCH
the specification of	which	en e	SEMICONDUCTOR	R DEVICES
(check one)				
is attached her	eto.			
was filed on				as
Application Ser	ial No			
and was amen	ded on	(if applicable)		
		and understand the contents of by any amendment referred to		specification,
I acknowledge the Title 37, Code of		se information which is materitions § 1.56.	ial to patentability a	s defined in
application(s) for p	patent or inventor for patent or inventor in the contract of t	nefits under Title 35, United Si or's certificate listed below and entor's certificate having a filing o	I have also identified	d below any
Prior Foreign Application(s)			Priorit	y Claimed
2002-279397 (Number)	Japam (Country)	25/09/2002 (Day/Month/Year Filed)	Yes	No
(Number)	(Country)	(Day/Month/Year Filed)	Yes	No
(Number)	(Country)	(Day/Month/Year Filed)	Yes	No
I hereby claim the b	enefit under Title	25 United States Code, 8120 c	of any I Inited States a	nnlication(e)

listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application:

POWER OF ATTORNEY

10WER OF ATTORNEY	•
The undersigned hereby authorizes the U.S. attorney or agent named herein to as to any action to be taken in the Patent and Twithout direct communication between the U.S. attorney or agent and the und persons from whom instructions may be taken, the U.S. attorney or agent named herein to a second secon	rademark Office regarding this application lersigned. In the event of a change in the
As a named inventor, I hereby appoint the following attorney(s) to prall business in the Patent and Trademark Office connected therewith: Andrew J. PATCH, Reg. No. 32,925, Robert F. HARGEST, Reg. No. 35,041, Eric JENSEN, Reg. No. 37,855, and Thomas W. PERKINS THOMPSON, Second Floor, 745 South 23rd Street, Arlington, Vi	Robert J. PATCH, Reg. No. 17,355, b. 25,590, Benoît CASTEL, Reg. No. S, Reg. No. 33,027, c/o YOUNG &
Address all telephone calls to Young & Thompson at 703/521-22	97.
I hereby declare that all statements made herein of my own knowl made on information and belief are believed to be true; and furth with the knowledge that willful false statements and the like s imprisonment, or both under Section 1001 of Title 18 of the Unit false statements may jeopardize the validity of the application or	ner that these statements were made o made are punishable by fine o ed States Code and that such willfu
Full name of sole or first inventor: (given name, family name) KAZUHIRO NAKAJIMA Inventor's signature KAZUHIRO NAKAJIMA	Date July 14, 2003
	Citizanshin
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Full name of second joint inventor, if any: (given name, family name) KOUJI KANBA	
Inventor's signature Koji Konba	Date July 14, 2003
Residence: Kanagawa, Japan	Citizenship: Japanese
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Full name of third joint inventor, if any: (given name, family name)	
Inventor's signature	Date
Residence:	Citizenship:

Post Office Address: